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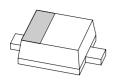
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PZUxB series

Single Zener diodes in a SOD323F package Rev. 02 — 15 November 2009

Product data sheet

Product profile

1.1 General description

General-purpose Zener diodes in a SOD323F (SC-90) very small and flat lead Surface Mounted Device (SMD) plastic package.

1.2 Features

- Total power dissipation: ≤ 310 mW
- Tolerance series: B: approximately ±5 %; B1, B2, B3: sequential, approximately ±2 %
- Small plastic package suitable for surface mounted design
- Wide working voltage range: nominal 2.4 V to 36 V

1.3 Applications

General regulation functions

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 100 \text{ mA}$	<u>[1]</u> -	-	1.1	V
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[2] _	-	310	mW
			[3] _	-	550	mW

^[1] Pulse test: $t_0 \le 300 \ \mu s$; $\delta \le 0.02$

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm².



Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard

Pinning information 2.

Table 2. **Pinning**

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	
2	anode	1 2	1 2 sym068

^[1] The marking bar indicates the cathode

3. **Ordering information**

Ordering information Table 3.

Type number	Package						
	Name	Description	Version				
PZU2.4B to PZU36B[1]	SC-90	plastic surface mounted package; 2 leads	SOD323F				

^[1] The series consists of 97 types with nominal working voltages from 2.4 V to 36 V.

Marking 4.

Table 4. Marking codes

Type number	Markir	ng code			Type number	Markir	Marking code			
	В	B1	B2	В3		В	B1	B2	B3	
PZU2.4	G3	-	-	-	PZU10	GJ	FH	HF	KB	
PZU2.7	G4	F3	H1	-	PZU11	GK	FJ	HG	KC	
PZU3.0	G5	F4	H2	-	PZU12	GL	FK	НН	KD	
PZU3.3	G6	F5	H3	-	PZU13	GM	FL	HJ	KE	
PZU3.6	G7	F6	H4	-	PZU14	-	-	HK	-	
PZU3.9	G8	F7	H5	-	PZU15	GN	FM	HL	KF	
PZU4.3	G9	F8	H6	HS	PZU16	GP	FN	НМ	KG	
PZU4.7	GA	F9	H7	HT	PZU18	GQ	FP	HN	KH	
PZU5.1	GB	FA	H8	HU	PZU20	GR	FQ	HP	KJ	
PZU5.6	GC	FB	H9	HV	PZU22	GS	FR	HQ	KK	
PZU6.2	GD	FC	HA	HW	PZU24	GT	FS	HR	KL	
PZU6.8	GE	FD	HB	HX	PZU27	GU	-	-	-	
PZU7.5	GF	FE	HC	HY	PZU30	GV	-	-	-	
PZU8.2	GG	FF	HD	HZ	PZU33	GW	-	-	-	
PZU9.1	GH	FG	HE	KA	PZU36	GX	-	-	-	

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Single Zener diodes in a SOD323F package

Limiting values 5.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
I _F	forward current		-	200	mA
I _{ZSM}	non-repetitive peak reverse current		-	see <u>Table 8</u> and <u>9</u>	
P _{ZSM}	non-repetitive peak reverse power dissipation		<u>[1]</u> _	40	W
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[2] -	310	mW
			[3] _	550	mW
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] $t_p = 100 \mu s$; square wave; $T_j = 25 \,^{\circ}C$ prior to surge

Thermal characteristics 6.

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	<u>[1]</u> -	-	400	K/W
	junction to ambient		[2] _	-	230	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[3] _	-	55	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. **Characteristics**

Product data sheet

Table 7. **Characteristics**

T_i = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 10 \text{ mA}$	[1] -	-	0.9	V
		I _F = 100 mA	[1] -	-	1.1	V

^[1] Pulse test: $t_0 \le 300 \ \mu s$; $\delta \le 0.02$

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm².

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm².

Soldering point of cathode tab



Table 8. Characteristics per type; PZU2.4B to PZU5.6B3

 $T_i = 25$ °C unless otherwise specified

PZU xxx	voltage $V_Z(V)$; $I_Z = 5 \text{ mA}$		e ;	Maximum differential resistance $\mathbf{r}_{\mathrm{dif}}\left(\Omega\right)$		Rever currer I _R (μΑ	nt	Temperature coefficient S_Z (mV/K); $I_Z = 5$ mA	capacitance C _d (pF)[1]	Non-repetitive peak reverse current I _{ZSM} (A)[2]	
		Min	Max	$I_Z = 0.5 \text{ mA}$	$I_Z = 5 \text{ mA}$	Max	V _R (V)	Тур	Max	Max	
2.4	В	2.3	2.6	1000	100	50	1	-1.6	450	8	
2.7	В	2.5	2.9	1000	100	20	1	-2.0	440	8	
	B1	2.5	2.75								
	B2	2.65									
3.0	В	2.80	3.20	1000	95	10	1	-2.1	425	8	
	B1	2.80	3.05								
	B2	2.95	3.20								
3.3	3.3 B 3.10 3.50		1000	95	5	1	-2.4	410	8		
	B1	3.10	3.35								
	B2	3.25	3.50								
3.6	3.6 B 3.40 3.80	1000	90	5	1	-2.4	390	8			
	B1	3.40	3.65								
	B2	3.55	3.80								
3.9	В	3.70	4.10	1000	90	3	1	-2.5	370	8	
	B1	3.70	3.97								
	B2	3.87	4.10					252			
4.3	В	4.01	4.48	1000	90	3	1	-2.5	350	8	
	B1	4.01	4.21								
	B2	4.15	4.34								
	B3	4.28	4.48								
4.7	В	4.42	4.90	800	80	2	1	-1.4	325	8	
	B1	4.42	4.61								
	B2	4.55	4.75								
E 1	B3	4.69	4.90	250	60	0	1 5	0.0	200	EE	
5.1	В	4.84	5.37	250	60	2	1.5	0.3	300	5.5	
	B1	4.84	5.04								
	B2	4.98	5.20								
5.6	B3	5.14	5.37	100	40	1	2 5	1.0	275	5.5	
5.6	B B1	5.31	5.92	100	40	1	2.5	1.9	275	5.5	
	B2	5.31	5.55								
		5.49 5.67	5.73								
	ВЗ	70.0	5.92								

^[1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}$

^[2] $t_p = 100 \ \mu s$; square wave; $T_j = 25 \ ^{\circ}C$ prior to surge



Table 9. Characteristics per type; PZU6.2B to PZU36B

 $T_i = 25$ °C unless otherwise specified

PZU xxx	Sel	Workir voltage V _Z (V); I _Z = 5 r	е	resistance				Temperature coefficient S_Z (mV/K); I_Z = 5 mA	capacitance	Non-repetitive peak reverse current I _{ZSM} (A)[2]	
		Min	Max	$I_Z = 0.5 \text{ mA}$	$I_Z = 5 \text{ mA}$	Max	V _R (V)	Тур	Max	Max	
6.2	В	5.86	6.53	80	30	500	3	2.7	250	5.5	
	B1	5.86	6.12								
	B2	6.06	6.33								
	ВЗ	6.26	6.53								
6.8	В	6.47	7.14	60	20	500	3.5	3.4	215	5.5	
	B1	6.47	6.73								
	B2	6.65	6.93								
	ВЗ	6.86	7.14								
	7.06	7.84	60	10	500	4	4.0	170	3.5		
	B1	7.06	7.36								
	B2	7.28	7.60								
	ВЗ	7.52	7.84								
8.2	В	7.76	8.64	60	10	500	00 5	4.6	150	3.5	
	B1	7.76	8.10								
	B2	8.02	8.36								
	ВЗ	8.28	8.64								
9.1	В	8.56	9.55	60	10	500	6	5.5	120	3.5	
	B1	8.56	8.93								
	B2	8.85	9.23								
	B3	9.15	9.55								
10	В	9.45	10.55	60	10	100	100 7	6.4	110	3.5	
	B1	9.45	9.87								
	B2	9.77	10.21								
	B3	10.11	10.55								
11	В	10.44	11.56	60	10	100	8	7.4	108	3	
	B1	10.44	10.88								
	B2	10.76	11.22								
	ВЗ	11.10	11.56								
12	В	11.42	12.60	80	10	100	9	8.4	105	3	
	B1	11.42	11.90								
	B2	11.74	12.24								
	B3	12.08	12.60					•			
13	В	12.47	13.96	80	10	100	10	9.4	103	2.5	
	B1	12.47	13.03								
	B2	12.91	13.49								
	B3	13.37	13.96								
14	B2	13.70	14.30	80	10	100	11	10.4	101	2	

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Single Zener diodes in a SOD323F package

Characteristics per type; PZU6.2B to PZU36B ...continued

 $T_i = 25$ °C unless otherwise specified

PZU xxx	xxx ve			Maximum differential resistance $\mathbf{r}_{\mathrm{dif}}\left(\Omega\right)$		current I _R (nA)		Temperature coefficient S_Z (mV/K); $I_Z = 5$ mA	Diode capacitance C _d (pF)[1]	Non-repetitive peak reverse current I _{ZSM} (A)[2]	
		Min	Max	$I_Z = 0.5 \text{ mA}$	$I_Z = 5 \text{ mA}$	Max	V _R (V)	Тур	Max	Max	
15	В	13.84	15.52	80	15	50	11	11.4	99	2	
	B1	13.84	14.46								
	B2	14.34	14.98								
	ВЗ	14.85	15.52								
16	В	15.37	17.09	80	20	50	12	12.4	97	1.5	
	B1	15.37	16.01								
	B2 15.85 16	16.51									
	ВЗ	16.35	17.09								
18	В	16.94	19.03	80	20	50	13	14.4	93	1.5	
	B1	16.94	17.70								
	B2	17.56	18.35								
	ВЗ	18.21	19.03								
20	В	18.86	21.08	100 20	20	50	15	16.4	88	1.5	
	В1	18.86 19.70									
	B2	19.52	20.39								
	ВЗ	20.21	21.08								
22	В	20.88	23.17	100	25	50	17	18.4	84	1.3	
	В1	20.88	21.77								
	B2	21.54	22.47								
	ВЗ	22.23	23.17								
24	В	22.93	25.57	120	30	50	19	20.4	80	1.3	
	В1	22.93	23.96								
	B2	23.72	24.78								
	ВЗ	24.54	25.57								
27	В	25.1	28.9	150	40	50	21	23.4	73	1	
30	В	28	32	200	40	50	23	26.6	66	1	
33	В	31	35	250	40	50	25	29.7	60	0.9	
36	В	34	38	300	60	50	27	33.0	59	0.8	

^[1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}$

Product data sheet

^[2] $t_p = 100 \mu s$; square wave; $T_j = 25 \,^{\circ}C$ prior to surge

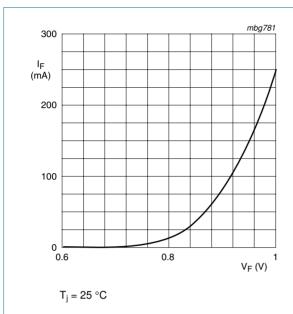


Fig 1. Forward current as a function of forward voltage; typical values

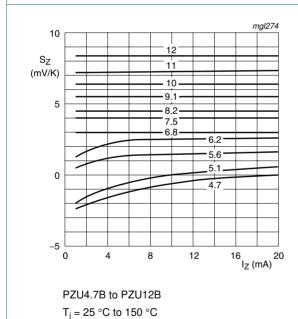
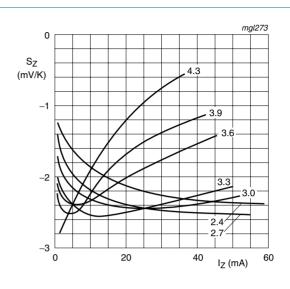
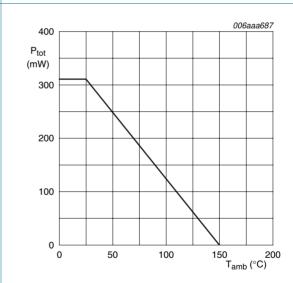


Fig 3. Temperature coefficient as a function of working current; typical values



PZU2.4B to PZU4.3B $T_i = 25 \, ^{\circ}\text{C}$ to 150 $^{\circ}\text{C}$

Temperature coefficient as a function of Fig 2. working current; typical values

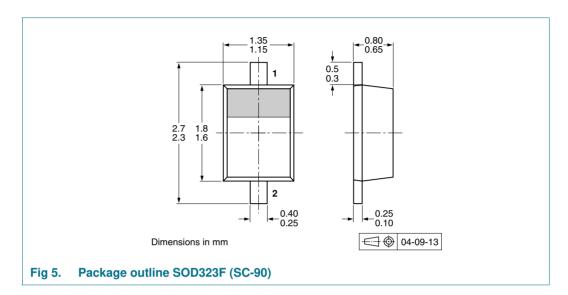


FR4 PCB, standard footprint

Fig 4. Power derating curve

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8. Package outline



9. Packing information

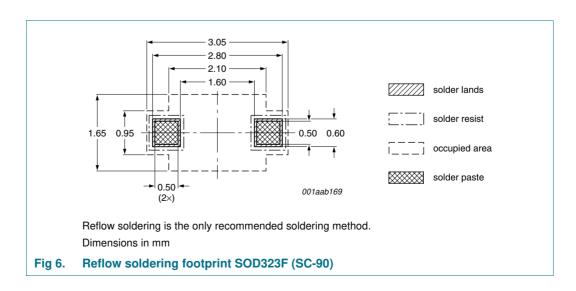
Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

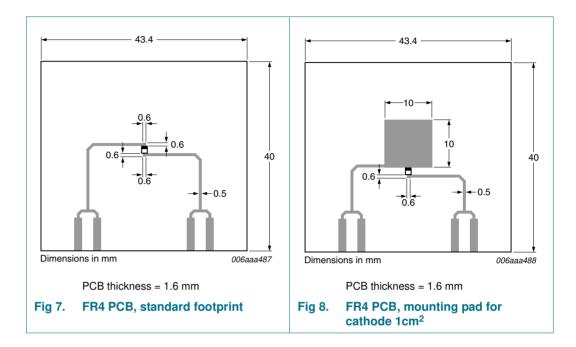
Type number	Package	Description	Packing quantity		
			3000	10000	
PZU2.4B to PZU36B	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135	

[1] For further information and the availability of packing methods, see Section 14.

10. Soldering



11. Mounting





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Single Zener diodes in a SOD323F package

12. Revision history

Table 11. Revision history

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
PZUXB_SER_2	20091115	Product data sheet	-	PZUXB_SER_1
Modifications:		neet was changed to reflect w legal definitions and dis		
PZUXB_SER_1	20060307	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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PZUxB series

Single Zener diodes in a SOD323F package

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